

FMMT495

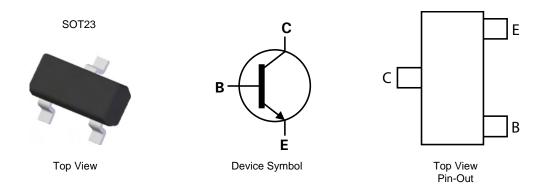
150V NPN SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT23

Feature

- BV_{CEO} > 150V
- I_C = 1A Continuous Collector Current
- I_{CM} = 2A Peak Pulse Current
- 500mW Power Dissipation
- h_{FE} characterised up to 1A for high current gain hold up
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <a>®3
- Weight 0.008 grams (approximate)



Ordering Information (Notes 4 & 5)

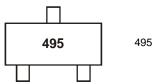
Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT495TA	AEC-Q101	495	7	8	3,000
FMMT495TC	AEC-Q101	495	13	8	10,000
FMMT495QTA	Automotive	495	7	8	3.000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com

Marking Information



495 = Product Type Marking Code





FMMT495

Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	170	V
Collector-Emitter Voltage	V _{CEO}	150	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current	I _{CM}	2	Α
Base Current	I _B	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P _D	500	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ heta JA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 7)	$R_{ heta JL}$	197	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	٧	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

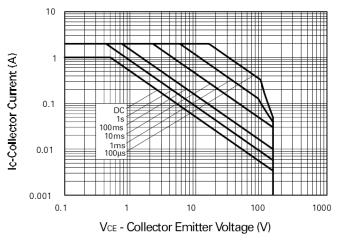
^{6.} For a device surface mounted on 15mm X 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

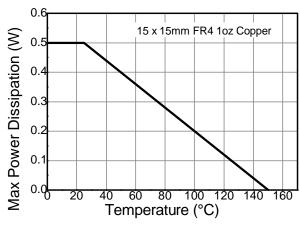
^{7.} Thermal resistance from junction to solder-point (at the end of the collector lead).

^{8.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.



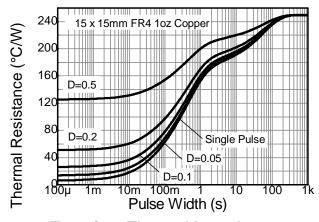
Thermal Characteristics and Derating Information

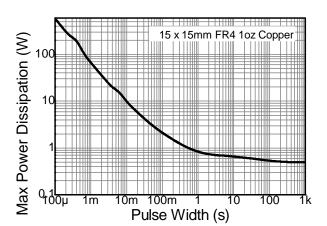




Safe Operating Area







Transient Thermal Impedance

Pulse Power Dissipation





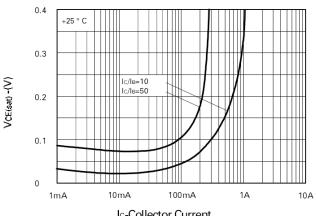
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	170	_	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	150	_	_	V	$I_C = 1mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	_	V	$I_{E} = 100 \mu A$
Collector Cutoff Current	I _{CBO}	_	_	100	nA	V _{CB} = 150V
Emitter Cutoff Current	I _{EBO}	_	_	100	nA	V _{EB} = 5V
Collector Emitter Cutoff Current	I _{CES}	_	_	100	nA	V _{CE} = 150V
	h _{FE}	100	_	_	_	$I_C = 1mA$, $V_{CE} = 10V$
Static Forward Current Transfer Ratio (Note 9)		100	_	300		$I_C = 250 \text{mA}, V_{CE} = 10 \text{V}$
Static Forward Current Transfer Ratio (Note 9)		50	_	_		$I_C = 500 \text{mA}, V_{CE} = 10 \text{V}$
		10	_	_		I _C = 1A, V _{CE} = 10V
Collector Emitter Seturation Voltage (Note 0)	V _{CE(sat)}	_	_	0.2	V	$I_C = 250 \text{mA}, I_B = 25 \text{mA}$
Collector-Emitter Saturation Voltage (Note 9)		_	_	0.3	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Base-Emitter Turn-On Voltage(Note 9)	V _{BE(on)}	_	_	1.0	V	$I_C = 500 \text{mA}, V_{CE} = 10 \text{V}$
Base-Emitter Saturation Voltage(Note 9)	V _{BE(sat)}	_	_	1.0	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Output Capacitance	C_obo	_	_	10	pF	V _{CB} = 10V, f = 1MHz
Transition Frequency	f _T	100	_	_	MHz	$V_{CE} = 10V, I_{C} = 50mA,$ f = 100MHz

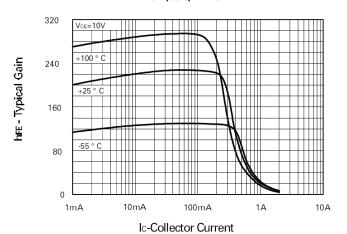
Notes: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



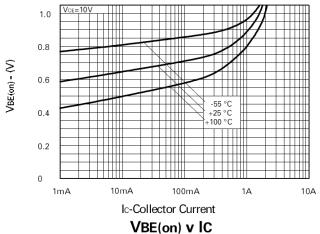
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

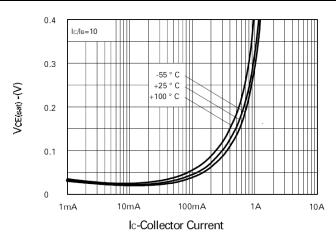


Ic-Collector Current VCE(sat) v IC

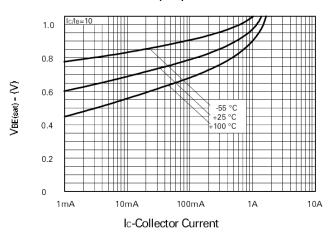


hFE V IC





VCE(sat) v IC

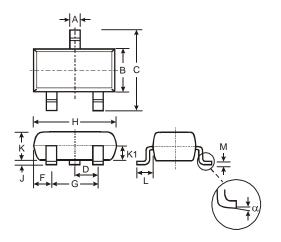


VBE(sat) v IC



Package Outline Dimensions

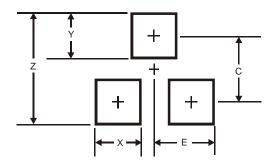
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
7	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K 1	-	-	0.400		
L	0.45	0.61	0.55		
M	0.085	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
Z	2.9			
Х	0.8			
Y	0.9			
С	2.0			
E	1.35			





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